



DOCUMENT CHANGE REQUEST

DCR number	414	Changes required for:	N/A	Originator:	Aissa Nehdi
Date:	2008/06/18	Date sent:	2008/06/18	Organisation:	CNES
Status:	IMPLEMENTED				

Title: Transistors Low Power PNP, based on type 2N5401

Number: 5202/014 Issue: 2

Other documents affected:

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2.4.1 Room Temperature Electrical Measurements
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Paragraph:

2.4.1 Room Temperature Electrical Measurements
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Original wording:

Proposed wording:

Small-Signal Current Gain h_{fe}
Test Condition : $V_{CE}=-10V; I_C=-10mA; f=10MHz$; Note 2
Limit Min : 5

Justification:

The original frequency condition for A.C. Forward Current Transfer Ratio (now Small-Signal Current Gain), 10kHz, was incorrect. Please note that STMicroelectronics has always tested this parameter using $f=10MHz$.

Attachments:
N/A
Modifications:
N/A
Approval signature:

Date signed:
2008-06-18